



EIT Opto-Routing

Silicon-germanium technology for optical interconnects



MPO-MPO Low Smoke Halogen
Free Sheath

Multimode 10 Gigabit 24 pole OM3

Insertion loss $<0.35\text{dB}$ Return loss $>50\text{dB}$





Overview

Silicon Germanium (SiGe) BiCMOS has a long track record of serving high-speed optical interconnect applications since the start of the Ethernet Gb/s era. Enabling higher per-lambda (λ) data rates, optical I/Os and packaging-aware integration, GF's silicon photonics solutions are redefining how bandwidth scales in next-generation scale-up and scale-out architectures. Artificial intelligence (AI) has become a transformative force across various industries, driving innovation and efficiency, but it's crucial to consider the sustainability of these advancements to ensure long-term benefits for society and the environment. The platform viability is experimentally and theoretically investigated through the realization of main building blocks of passive circuitry. Integration of optical data communication with electrical data computing via Si complementary metal-oxide-semiconductor (CMOS) technology could revolutionize information technology. To meet the unprecedented demands for data transmission speed and bandwidth silicon integrated photonics that can generate, modulate, process and detect light signals is being developed.



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Three-Dimensional Silicon-Germanium Nanostructures for CMOS

1. Introduction Optical interconnects in the form of fiber optics have been used for many years in different long-distance communication applications [1, 2]. With the microprocessor clock

At \$122.90, most of the upside is already in the price. \$AXTI has

In optical communication systems, the absolute metric dictating transmission distance and quality is the wavelength of light. When light travels through silica-based optical fibers, signal



Ge-rich silicon germanium as a new platform for optical interconnects

We propose germanium-rich silicon-germanium (SiGe) as a new platform for optical interconnects. The platform viability is experimentally and theoretically investigated through the realization of main

High-performance Ge photodetectors on silicon photonics platform for

Silicon-based Ge photodetectors, as the core devices in silicon-based integrated optoelectronic systems, have received considerable attention due to their superior electrical and

Special silicon-germanium alloy holds promise for

Light emission from silicon-based materials has long been the 'holy grail' of microelectronics. EU-funded researchers created a hexagonal form of silicon-germanium, a unique

Marvell bets big on optical interconnects, buying

Chipmaker Marvell Technology Inc. said today it has agreed to acquire a networking startup called Celestial AI Inc. that's developing optical interconnect

Silicon photonics just gained a powerful new ally, and it could reshape

The popularity of cloud computing and AI--driving massive data flows--pushes demand for ultra-high-speed, energy-efficient optical links within and between data centers; links that must be



Advancing High-Performance Silicon Photonics and Silicon

GF uniquely enables co-integration of silicon photonics and SiGe, delivering a streamlined, end-to-end solution spanning optics, electrical ICs and advanced packaging.

Integrated germanium optical interconnects on silicon substrates

In this Article, we present a new approach to monolithically integrate low-voltage, broadband photonic interconnections on a bulk Si platform.



Silicon Photonics Driving AI Data Center Innovation

Leading Companies Advancing Silicon Photonics Innovation The silicon photonics industry is supported by several major technology and semiconductor companies that are actively contributing

Conceptual illustration of a photonically interconnected macrochip

For even tighter integration of optical interconnects with switch and processor ASICs, we discuss photonic multi-chip module and interposer packaging technologies that will further improve system

Silicon germanium on graded buffer as a new platform for optical

The system composed of Germanium (Ge) rich Si $1-x$ Ge x guiding layer on a graded



SiGe layer is shown to be suitable for the realization of all main building blocks of passive optical circuitry.

All AI Data Center Interconnects Will Be Optical Within 5 Years

All AI Data Center Interconnects Will Be Optical Within 5 Years InP and SiPho join CMOS as critical technologies. Lasers, CPO and OCS will be everywhere (indium phosphide, silicon

Silicon Photonic Transceiver Module Technology 2026 , PatSnap

Technology Overview CMOS-Compatible Photonics Powering Next-Generation Data Links
Silicon photonic transceiver modules leverage silicon-on-insulator waveguides, Mach-Zehnder



SOI Technology Lights Up the Next Wave of Photonics

Based on this process, SOI technology can now replace traditional copper lines in data interconnects with submicrometer-wide silicon waveguides that send,

TSEM Q4-2025 Earnings Call

Silicon photonics and silicon germanium experienced significant expansion, with record revenues and a growing share of corporate revenue. RF infrastructure revenue jumped 75% year

Instagram



Silicon Germanium (SiGe) is a semiconductor material that combines silicon with germanium to improve transistor speed, power efficiency, and high-frequency performance. It is widely used in RF chips,

Monolithic electro-optic platform on silicon with bandwidth of

We demonstrate a scalable C-band silicon photonic platform monolithically integrating ultra-high speed germanium-silicon electro absorption modulators and fin photodiodes.

Global Silicon Photonics Market Report 2025-2035, with Profiles of

2.9 Core Technology Components 2.10 Basic Optical Data Transmission 2.11 Silicon Photonic Circuit Architecture 3 MATERIALS AND COMPONENTS 3.1 Silicon 3.2 Germanium 3.3



Advancing High-Performance Silicon Photonics and

GF uniquely enables co-integration of silicon photonics and SiGe, delivering a streamlined, end-to-end solution spanning optics, electrical ICs and

Room temperature operation of germanium-silicon

A germanium-silicon single-photon avalanche diode operated at room temperature shows a noise-equivalent power improvement over the

Silicon germanium on graded buffer as a new platform for optical

We experimentally and theoretically investigate the use of silicon germanium (SiGe) on



silicon substrate as a new platform for optical interconnects. The system composed of Germanium (Ge) rich Si $1-x$ Ge

Tower semiconductor rides silicon photonics wave

Tower Semiconductor has caught a wave of demand for chips supporting the AI boom, the company president Marco Racanelli told EE Times.

Germanium-on-Silicon for Integrated Silicon Photonics

This chapter discusses the research of using germanium and GeSi for silicon-integrated photodetection and light source in the contexts of material physics and growth, device design and fabrication.



Monolithically Integrated Germanium Photodetector and Planar

ABSTRACT We present a millimeter-wave (mm-wave) emitter featuring a monolithically integrated, high-performance germanium (Ge) photodetector (PD) coupled with an impedance

ST silicon photonics and BiCMOS technologies: the winning portfolio

Silicon Germanium (SiGe) BiCMOS has a long track record of serving high-speed optical interconnect applications since the start of the Ethernet Gb/s era. It is considered the best technology for

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